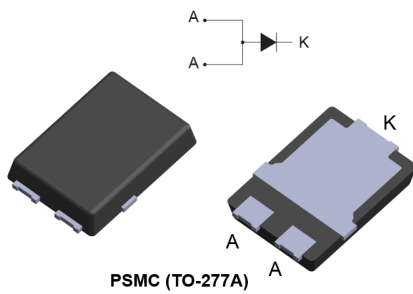


## 100 V power Schottky rectifier



### Features

- Low profile design – package height of 1.1 mm typ.
- Wettable flanks for automatic visual inspection
- Low forward voltage drop
- Avalanche capability
- ECOPACK<sup>®</sup>2 compliant

### Applications

- Switching diode
- Notebook adapter
- LED lighting
- DC/DC converter

### Description

This high voltage Schottky barrier rectifier has been optimized for use in high frequency miniature DC/DC converters, reverse battery protection, battery chargers and adaptors.

Packaged in PSMC (TO-277A), the **STPS5H100SF** provides a high level of performance in a compact and flat package which can withstand very high operating junction temperature.

Product status link	
<a href="#">STPS5H100SF</a>	
Product summary	
Symbol	Value
$I_{F(AV)}$	5 A
$V_{RRM}$	100 V
$T_j$ (max.)	175 °C
$V_F$ (typ.)	0.545 V

# 1 Characteristics

**Table 1. Absolute ratings (limiting values at 25 °C, unless otherwise specified, anode terminals short-circuited)**

Symbol	Parameter	Value	Unit
V <sub>RRM</sub>	Repetitive peak reverse voltage	100	V
I <sub>F(AV)</sub>	Average forward current, $\delta = 0.5$ square wave	T <sub>c</sub> = 160 °C	5 A
I <sub>FSM</sub>	Surge non repetitive forward current	t <sub>p</sub> = 10 ms sinusoidal	230 A
P <sub>ARM</sub>	Repetitive peak avalanche power	t <sub>p</sub> = 10 $\mu$ s, T <sub>j</sub> = 125 °C	518 W
T <sub>stg</sub>	Storage temperature range	-65 to +175	°C
T <sub>j</sub>	Maximum operating junction temperature <sup>(1)</sup>	+175	°C

1.  $(dP_{tot}/dT_j) < (1/R_{th(j-a)})$  condition to avoid thermal runaway for a diode on its own heatsink.

**Table 2. Thermal resistance parameters**

Symbol	Parameter	Typ.	Unit
R <sub>th(j-c)</sub>	Junction to case	2.1	°C/W

For more information, please refer to the following application note:

- AN5088: Rectifiers thermal management, handling and mounting recommendations

**Table 3. Static electrical characteristics (anode terminals short-circuited)**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
I <sub>R</sub> <sup>(1)</sup>	Reverse leakage current	T <sub>j</sub> = 25 °C	-		8	$\mu$ A
		T <sub>j</sub> = 125 °C	-	1.5	5	mA
V <sub>F</sub> <sup>(2)</sup>	Forward voltage drop	T <sub>j</sub> = 25 °C	-		0.640	V
		T <sub>j</sub> = 125 °C	-	0.480	0.540	
		T <sub>j</sub> = 25 °C	-		0.745	
		T <sub>j</sub> = 125 °C	-	0.545	0.610	

1. Pulse test: t<sub>p</sub> = 5 ms,  $\delta < 2\%$

2. Pulse test: t<sub>p</sub> = 380  $\mu$ s,  $\delta < 2\%$

To evaluate the conduction losses, use the following equation:

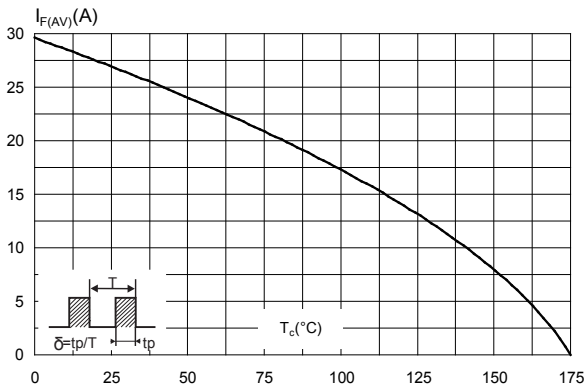
$$P = 0.470 \times I_{F(AV)} + 0.028 \times I_{F(RMS)}^2$$

For more information, please refer to the following application notes related to the power losses:

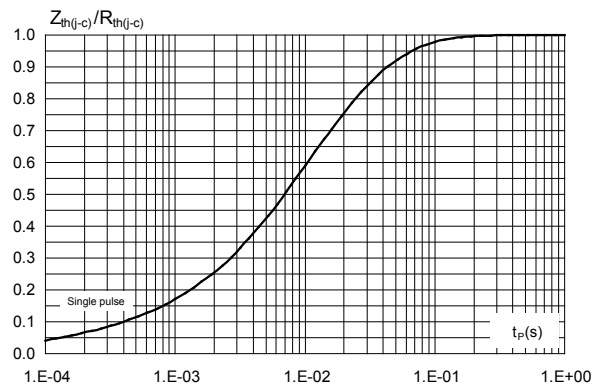
- AN604: Calculation of conduction losses in a power rectifier
- AN4021: Calculation of reverse losses in a power diode

### 1.1 Characteristics (curves)

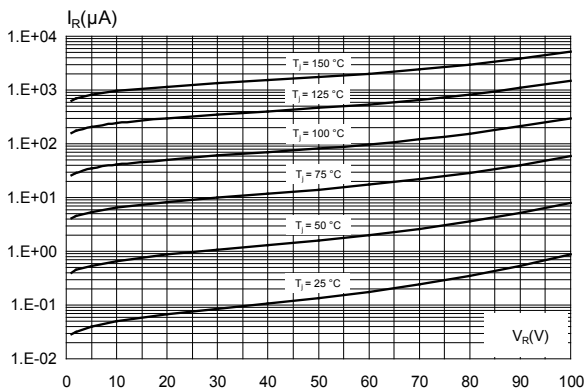
**Figure 1. Average forward current versus case temperature ( $\delta = 0.5$ )**



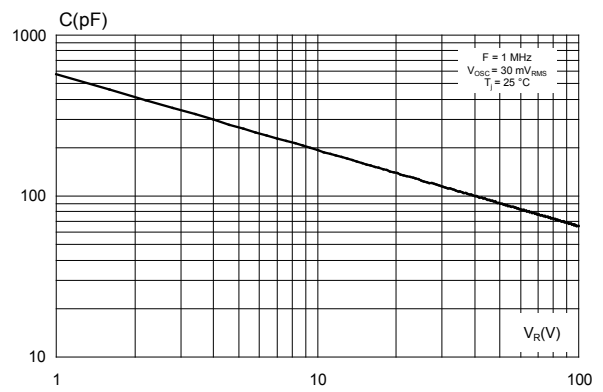
**Figure 2. Relative variation of thermal impedance junction to case versus pulse duration**



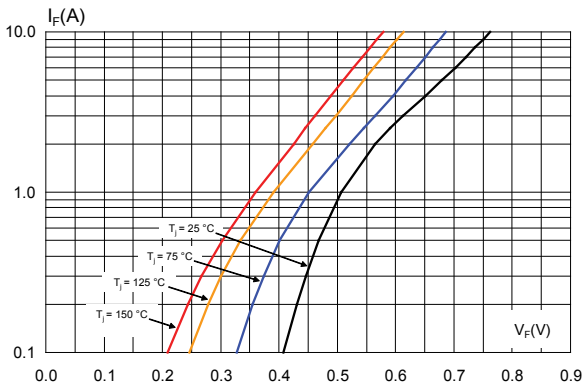
**Figure 3. Reverse leakage current versus reverse voltage applied (typical values)**



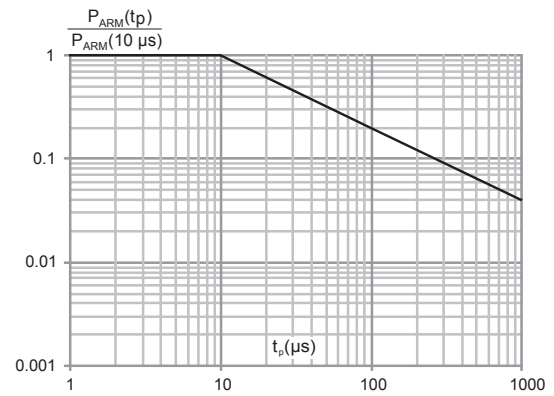
**Figure 4. Junction capacitance versus reverse voltage applied (typical values)**



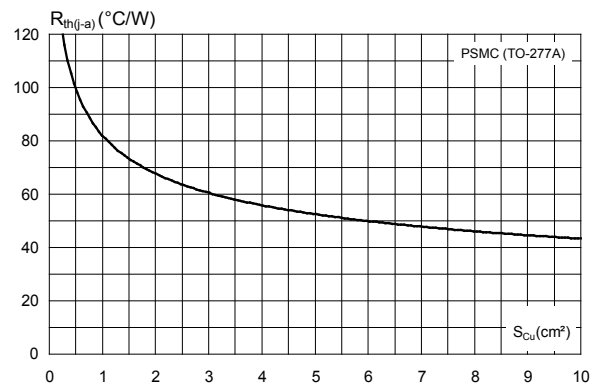
**Figure 5. Forward voltage drop versus forward current (typical values)**



**Figure 6. Normalized avalanche power derating versus pulse duration ( $T_j = 125^\circ\text{C}$ )**



**Figure 7. Thermal resistance junction to ambient versus copper surface under tab (typical values, epoxy printed board FR4,  $e_{\text{Cu}} = 35\ \mu\text{m}$ ) (PSMC (TO-277A))**



## 2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK® is an ST trademark.

### 2.1 PSMC (TO-277A) package information

- Epoxy meets UL94,V0
- Cooling method : by conduction (C)

Figure 8. PSMC (TO-277A) package outline

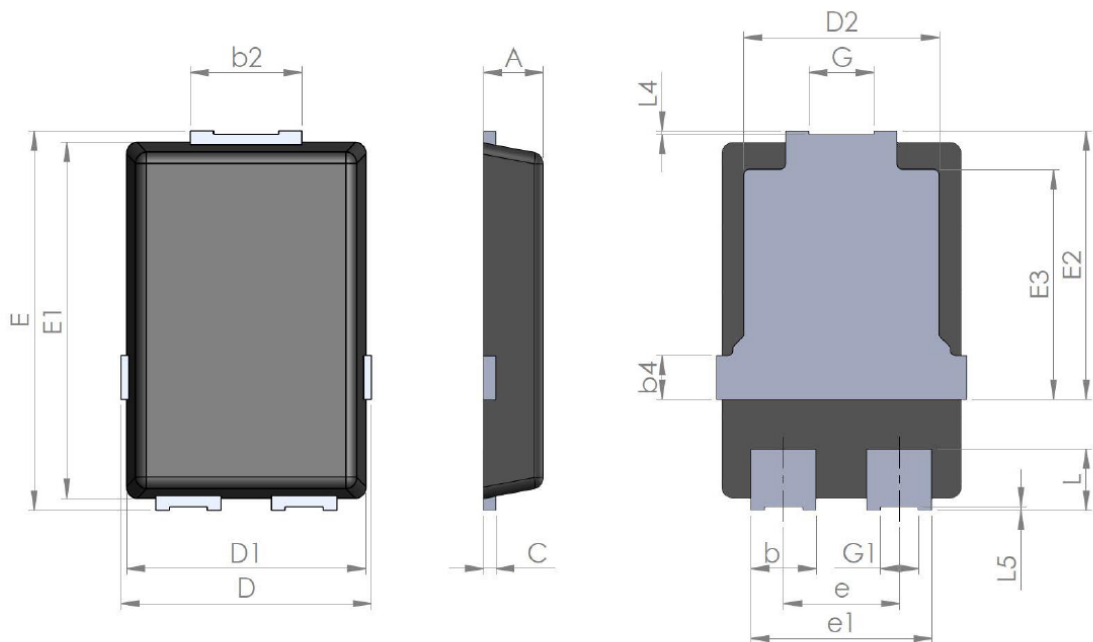


Table 4. PSMC (TO-277A) package mechanical data

Ref.	Dimensions					
	Millimeters			Inches (for reference only)		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	1.00	1.10	1.20	0.039	0.043	0.047
b	1.05	1.20	1.35	0.041	0.047	0.053
b2	1.90	2.05	2.20	0.075	0.081	0.087
b4		0.75			0.029	
C	0.15	0.23	0.40	0.006	0.009	0.016
D	4.45	4.60	4.75	0.175	0.181	0.187
D1	4.25	4.40	4.45	0.167	0.173	0.175
D2	3.40	3.60	3.70	0.134	0.142	0.146



### 3 Ordering information

**Table 5. Ordering information**

Order code	Marking	Package	Weight	Base qty.	Delivery mode
STPS5H100SF	PS5H100	PSMC (TO-277A)	90 mg	6000	Tape and Reel

## Revision history

**Table 6. Document revision history**

Date	Version	Changes
30-Jul-2018	1	Initial release.



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